

Form PTO-1449	U.S. DEPT. OF COMMERCE Patent and Trademark Office	Atty. Docket No.: 351913-992740	Serial No.: 10/714,243
INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)		Applicants: Chen, et al.	
		Filing Date: November 13, 2003	Group Art Unit: 2818

U.S. PATENT DOCUMENTS

Examiners Initials	Patent Number	Date	Name	Class	Subclass	Filing Date
<i>dh</i>	2002/0056870 A1	05-2002	Lee et al			
	2002/0163031 A1	11-2002	Lee et al			
	2004/0087084 A1	05-2004	Hsieh			
	5,021,999	06-1991	Kohda et al			
	5,029,130	07-1991	Yeh			
	5,739,567	04-1998	Wong			
	5,768,192	06-1998	Eitan			
	6,002,152	12-1999	Guterman et al			
	6,011,725	01-2000	Eitan			
	6,093,945	07-2000	Yang, Yu-Hao			
	6,103,573	08-2000	Harari et al			
	6,151,248	11-2000	Harari et al			
	6,281,545	08-2001	Liang et al			
	6,329,685	12-2001	Lee			
	6,420,231	07-2002	Harari et al			
	6,426,896	07-2002	Chen			
	6,541,815	04-2003	Mandelman			
<i>dh</i>	6,597,036	07-2003	Lee et al			

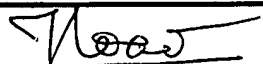
Examiner: <i>Woo</i>	Date Considered: <i>02/12/2006</i>
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP '609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.	

FOREIGN PATENT DOCUMENTS

Document number	Date	Country	Class	Sub-class	Translation	
					YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

dh	IEEE, 2002, entitled "Quantum-well Memory Device (QW/MD) With Extremely Good Charge Retention," Z. Krivokapic, et al. (4 pages)

Examiner:		Date Considered:	02/12/06
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP '609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.			